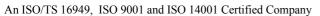
Continental Device India Limited







SOT-23 Formed SMD Package

BC807 BC808

SILICON PLANAR EPITAXIAL TRANSISTORS

P-N-P transistor

Marking

BC807 = 5D

BC807-16 = 5A

BC807-25 = 5B

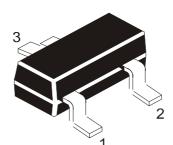
BC807-40 = 5C

BC808 = 5H

BC808-16 = 5E

BC808-25 = 5F

BC808-40 = 5G



BC807

B*C808*

mAmW ${}^{\circ}\!C$

MHz

Pin configuration

1 = BASE 2 = EMITTER

3 = COLLECTOR



ABSOLUTE MAXIMUM RATINGS

Collector-emitter voltage ($V_{BE} = 0$)	$-V_{CES}$	max.	50	30	\overline{V}
Collector-emitter voltage (open base)	−V _{CE0}	max.	45	25	V
Collector current (peak value)	-I _{CM}	max.	10	000	mΑ
Total power dissipation up to $T_{amb} = 25 ^{\circ}C$	P_{tot}	max.	2	50	mW
Junction temperature	T_j	max.	1	50	${}^{\circ}\!C$
Transition frequency at $f = 100 \text{ MHz}$	•				
$-I_C = 10 \text{ mA; } -V_{CE} = 5 \text{ V}$	f_T	>	8	<i>30</i>	MHz

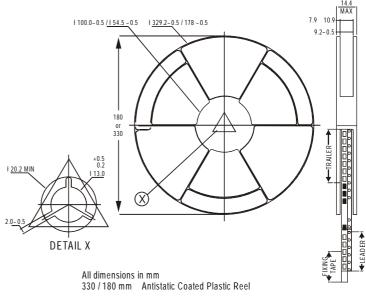
RATINGS (at $T_A = 25^{\circ}C$ unless	otherwise specif	ied)					
Limiting values				BC807	E	C80	8
Collector-emitter voltage (V_{BE} =	0)	$-V_{CES}$	max	. 50		30	V
Collector-emitter voltage (open	base)						
$-I_C = 10 \text{ mA}$		-V _{CE0}	max	. 45		25	V
Emitter-base voltage (open colle	ector)	−V _{EB0}	max	. 5		5	V
Collector current (DC)		$-I_C$	max		500		mΑ
Collector current (peak value)		-I _{CM}	max		1000		mΑ
Emitter current (peak value)		I_{EM}	max		1000		mΑ
Base current (DC)		$-I_B$	max		100		mΑ
Base current (peak value)		$-I_{BM}$	max		200		mΑ
Total power dissipation at T _{amb}	= 25 °C *	P_{tot}	max		<i>250</i>		mW
Storage temperature		T_{stg}		-55	to +15	0	${}^{\!$
Junction temperature		T_j	max		150		${}^{\!$
THERMAL RESISTANCE*							
From junction to ambient		$R_{th j-a}$	=		<i>500</i>		K/W
CHARACTERISTICS							
$T_i = 25$ °C unless otherwise spec	cified						
Collector cut-off current							
$I_E = 0$; $-V_{CB} = 20V$; $T_i = 25^\circ$	$^{\circ}C$			-I _{CB0}	max.	100	nΑ
$I_E = 0$; $-V_{CB} = 20V$; $T_i = 150$				-I _{CB0}	max.		μΑ
Emitter cut-off current				СБО			•
$I_C = 0; \ V_{EB} = 5 \ V$				-I _{EB0}	max.	10	μΑ
Base emitter voltage *				LDU			•
$-I_C = 500 \text{ mA}; -V_{CE} = 1 \text{ V}$				$-V_{BE}$	max.	1,2	V
Saturation voltage				DL			
$-I_C = 500 \text{ mA}; -I_B = 50 \text{ mA}$				-V _{CEsat}	max.	700	mV
D.C. current gain				_			
$-I_C = 500 \text{ mA; } -V_{CE} = 1 \text{ V}$				h_{FE}	min.	40	
$-I_C = 100 \text{ mA}; -V_{CE} = 1 \text{ V};$	BC807; BC808		1	h_{FE}	100 to	600	
	BC807-16 BC808-16		1	h_{FE}	100 to	250	
	BC807-25 BC808-25		1	h_{FE}	160 to	400	
	BC807-40 BC808-40		1	h_{FE}	250 to	600	
Transition frequency at $f = 100 \text{ f}$ $-I_C = 10 \text{ mA}$; $-V_{CE} = 5 \text{ V}$			i	f_T	>	80	MHz
Collector capacitance at $f = 1 M$ $I_E = I_e = 0$; $-V_{CB} = 10 V$	HZ		(C_c	typ.	8	рF

SOT-23 Formed SMD Package

+/- 0.05 0.62 1.30----+/-0.05 0.62 +/-0.025 1.90 cL 3 - 0.05 - 1.30 +/- 0.05 0.62 I← 0.62 0.08 0.08 MIN MIN PARTING LINE RO.08 0.21

2.50 +/-0.10

SOT-23 Package Reel Information Reel specifications for Packing (13"/7" reels)



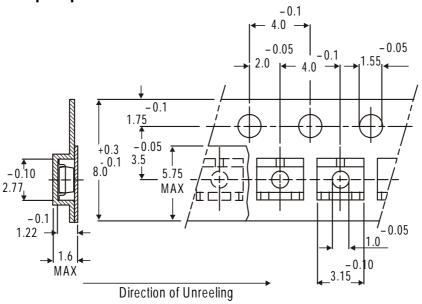
 NOTES:
 8mm Tape
 8mm Tape

 Size of Reel
 330 mm (13")
 180 mm (7")

 No. of Devices
 10,000 Pcs
 3,000 Pcs

- 1. The bandolier of 330 mm reel contains at least 10,000 devices.
- 2. The bandolier of 180 mm reel contains at least 3,000 devices.
- No more than 0.5% missing devices / reel. 50 empty compartments for 330 mm reel.
 15 empty compartments for 180 mm reel.
- Three consecutive empty places might be found provided this gap is followed by 6 consecutive devices.
- The carrier tape (leader) starts with at least 75 empty positions (equivalent to 330 mm). In order to fix the carrier tape a self adhesive tape of 20 to 50 mm is applied. At the end of the bandolier at least 40 empty positions (equivalent to 160 mm) are there.

Tape Specification for SOT-23 Surface Mount Device



Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX			
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt	
SOT-23 T&R	3K/reel	136 gm/3K pcs	3" x 7.5" x 7.5" 9" x 9" x 9"	12.0K 51.0K	17" x 15" x 13.5" 19" x 19" x 19"	192.0K 408.0K	12 kgs 28 kgs	
	10K/reel	415 gm/10K pcs	13" x 13" x 0.5"	10.0K	17" x 15" x 13.5"	300.0K	16 kgs	

Customer Notes

Component Disposal Instructions

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
 - 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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